NSN 5962-01-110-7714

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View Online at https://aerobasegroup.com/nsn/5962-01-110-7714
Body Length:
Between 1.068 inches and 1.092 inches
Body Width:
Between 0.378 inches and 0.398 inches
Body Height:
Between 0.080 inches and 0.115 inches
Maximum Power Dissipation Rating:
578.0 milliwatts
Operating Tempurature Range:
55.0/+125.0 degrees celsius
Storage Tempurature Range:
65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/storage and high speed and low power and w/enable
nclosure Material:
Ceramic and glass
nclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
nput Circuit Pattern:
14 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level
putput
Memory Device Type:
Ram
Memory Capacity:
Jnknown
Test Data Document:
20551-a630 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
22 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli

Demilitarization:

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